

Device Modeling Report

COMPONENTS: MOSFET (Model Parameters)
PART NUMBER: 2SK4066-DL-E
MANUFACTURER: SANYO
REMARK: Body Diode (Model Parameters) /
ESD Protection Diode



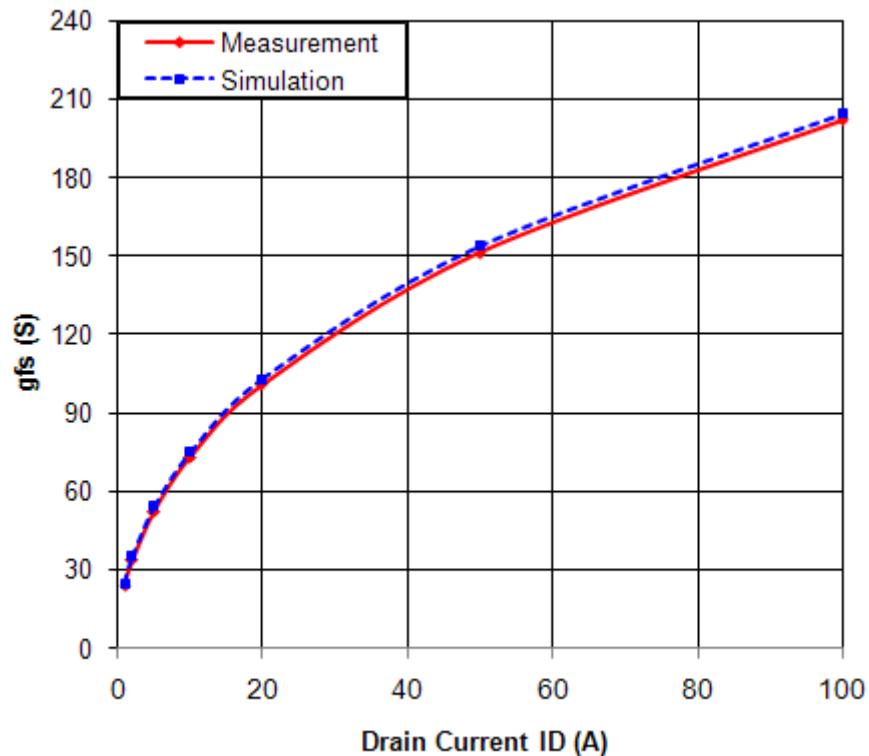
Bee Technologies Inc.

MOSFET MODEL

PSpice model parameter	Model description
LEVEL	
L	Channel Length
W	Channel Width
KP	Transconductance
RS	Source Ohmic Resistance
RD	Ohmic Drain Resistance
VTO	Zero-bias Threshold Voltage
RDS	Drain-Source Shunt Resistance
TOX	Gate Oxide Thickness
CGSO	Zero-bias Gate-Source Capacitance
CGDO	Zero-bias Gate-Drain Capacitance
CBD	Zero-bias Bulk-Drain Junction Capacitance
MJ	Bulk Junction Grading Coefficient
PB	Bulk Junction Potential
FC	Bulk Junction Forward-bias Capacitance Coefficient
RG	Gate Ohmic Resistance
IS	Bulk Junction Saturation Current
N	Bulk Junction Emission Coefficient
RB	Bulk Series Resistance
PHI	Surface Inversion Potential
GAMMA	Body-effect Parameter
DELTA	Width effect on Threshold Voltage
ETA	Static Feedback on Threshold Voltage
THETA	Mobility Modulation
KAPPA	Saturation Field Factor
VMAX	Maximum Drift Velocity of Carriers
XJ	Metallurgical Junction Depth
UO	Surface Mobility

Transconductance Characteristic

Circuit Simulation Result

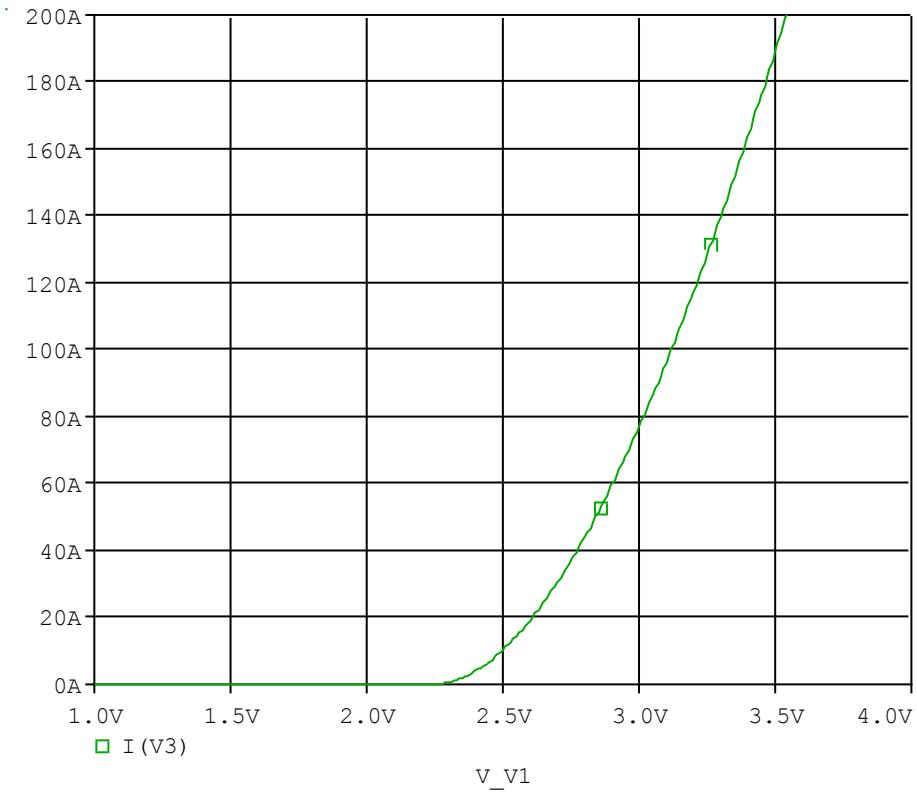


Comparison table

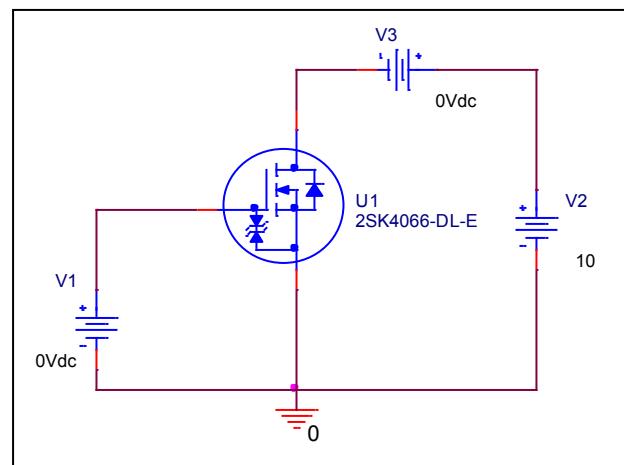
Id(A)	g_{fs} (s)		Error (%)
	Measurement	Simulation	
1	24.000	24.929	3.87
2	33.750	34.985	3.66
5	52.500	54.267	3.37
10	73.000	75.091	2.86
20	101.000	103.013	1.99
50	151.000	153.696	1.79
100	202.000	204.355	1.17

V_{gs}-I_d Characteristic

Circuit Simulation result

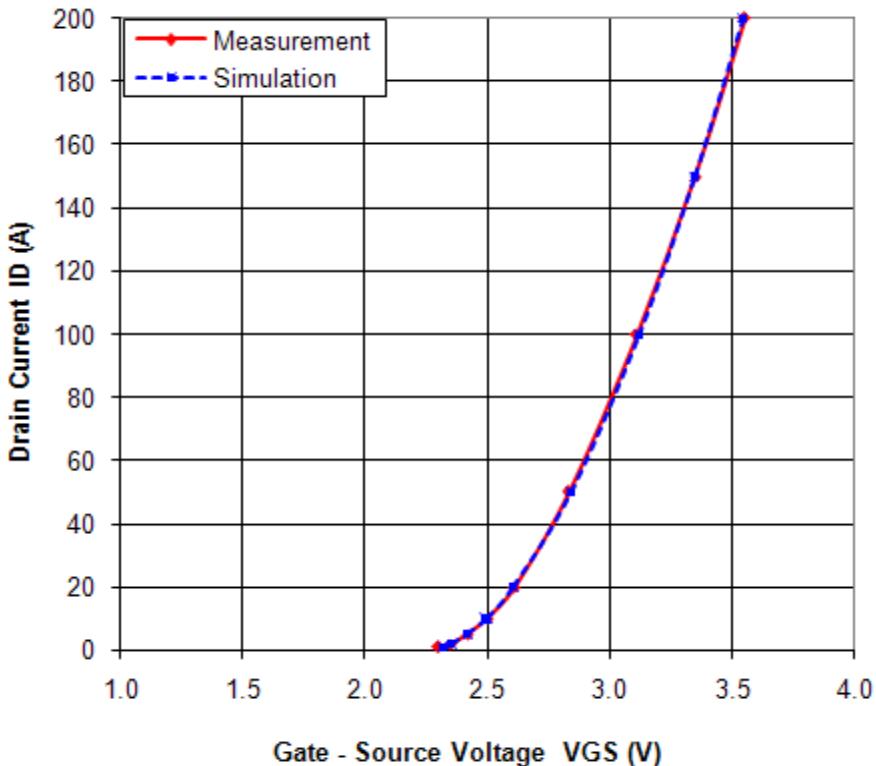


Evaluation circuit



Comparison Graph

Circuit Simulation Result

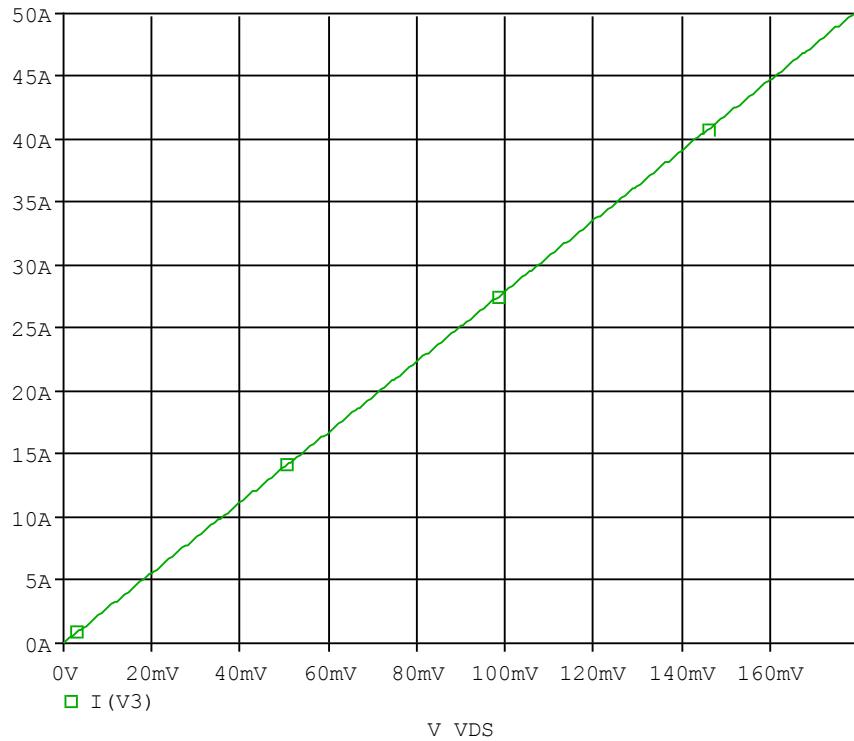


Simulation Result

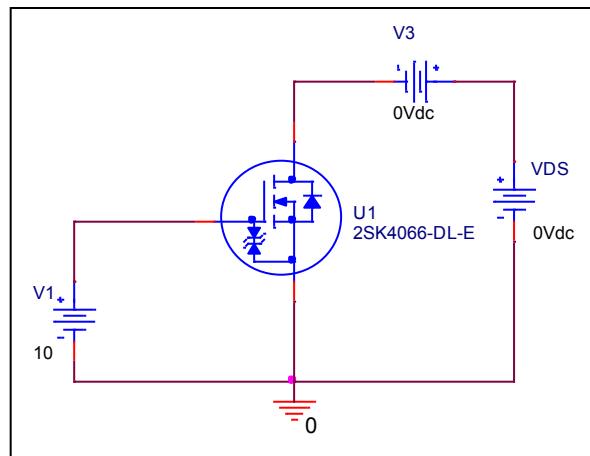
I_D (A)	V_{GS} (V)		Error (%)
	Measurement	Simulation	
1	2.300	2.318	0.783
2	2.350	2.352	0.085
5	2.420	2.419	-0.041
10	2.500	2.496	-0.160
20	2.610	2.608	-0.077
50	2.830	2.840	0.353
100	3.110	3.118	0.257
150	3.350	3.344	-0.179
200	3.550	3.541	-0.254

Rds(on) Characteristic

Circuit Simulation result



Evaluation circuit

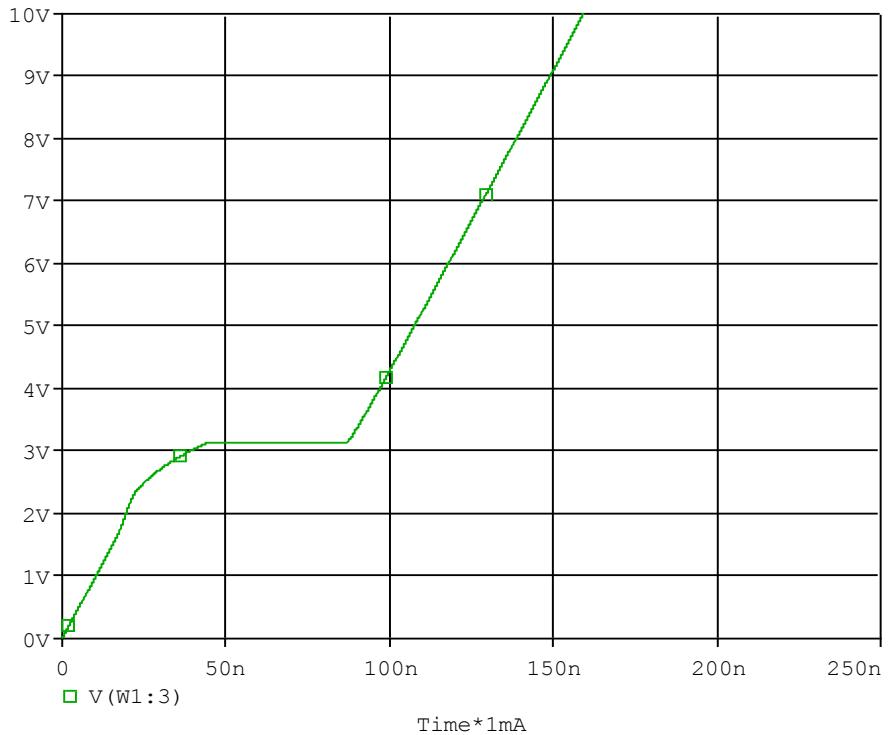


Simulation Result

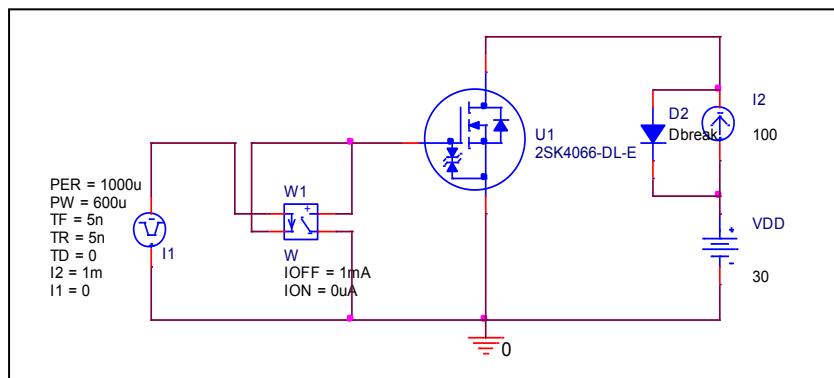
I_D = 50A, V_{GS} = 10V		Measurement	Simulation	Error (%)
R_{DS} (on)	mΩ	3.600	3.579	-0.58

Gate Charge Characteristic

Circuit Simulation result



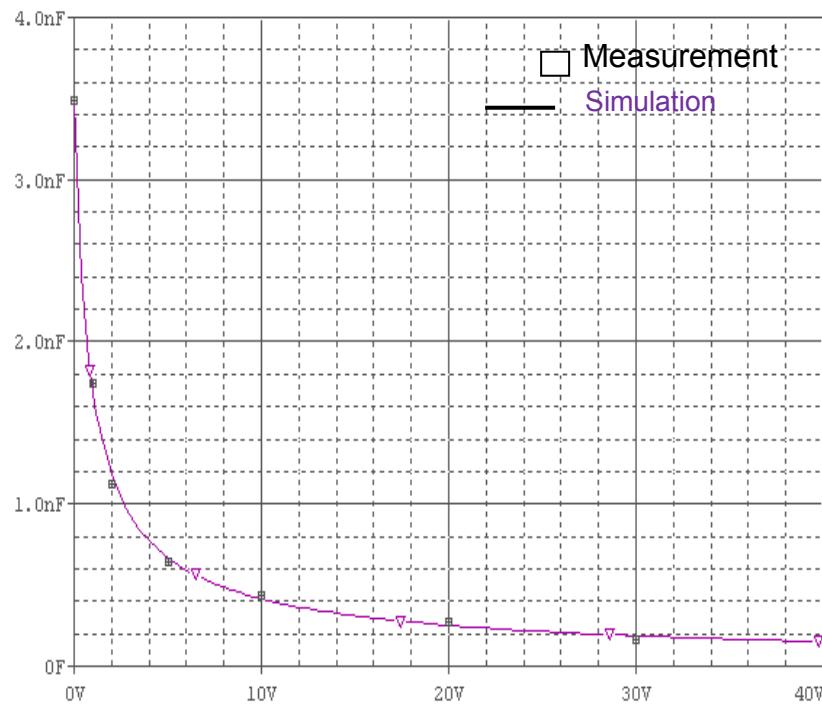
Evaluation circuit



Simulation Result

$V_{DD}=30V, I_D=100A, V_{GS}=10V$		Measurement	Simulation	Error (%)
Qgs	nC	31.000	31.266	0.86
Qgd	nC	55.000	55.892	1.62
Qg	nC	220.000	159.307	-27.59

Capacitance Characteristic

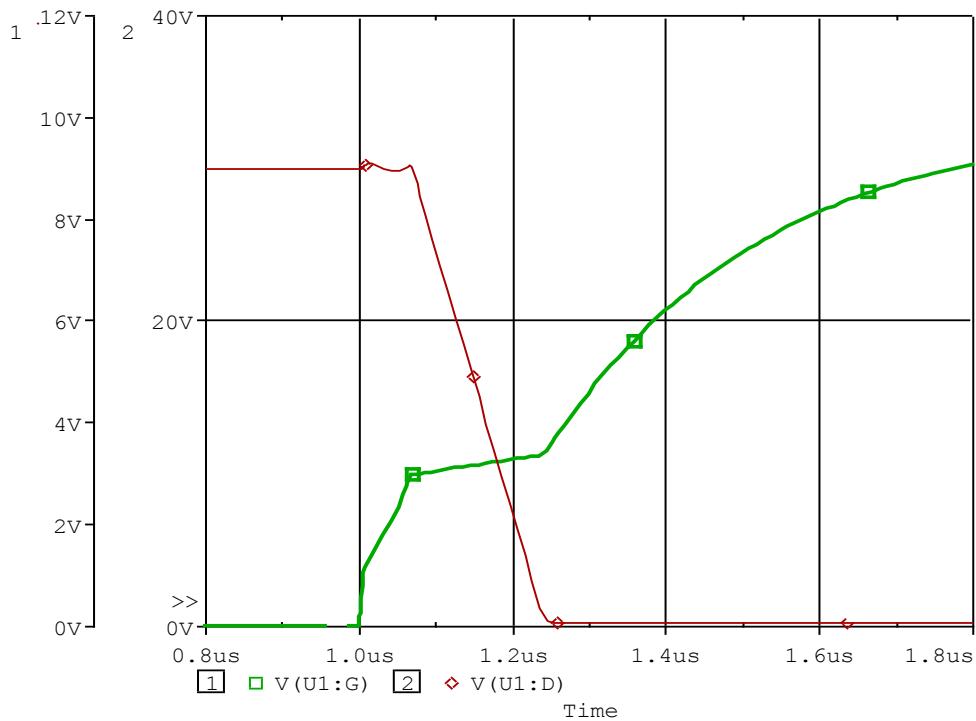


Simulation Result

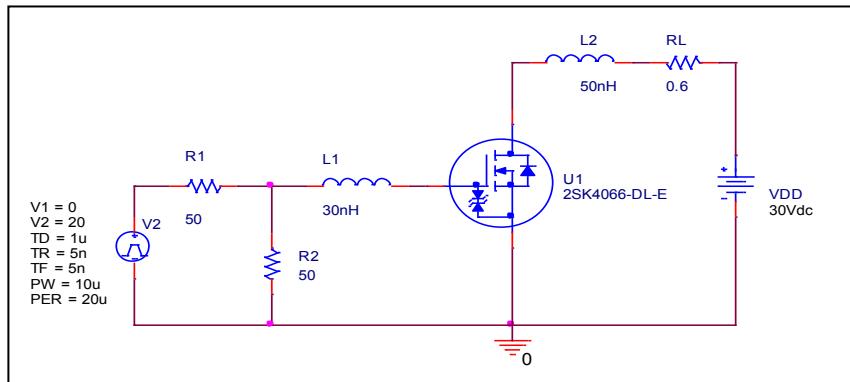
V_{ds} (V)	Cbd (pF)		Error (%)
	Measurement	Simulation	
0.0	3500.00	3490.000	-0.29
1.0	1750.00	1745.000	-0.29
2.0	1200.00	1210.000	0.83
5.0	670.00	680.000	1.49
10.0	425.00	420.000	-1.18
20.0	265.00	260.000	-1.89
30.0	175.00	180.000	2.86

Switching Time Characteristic

Circuit Simulation result



Evaluation circuit

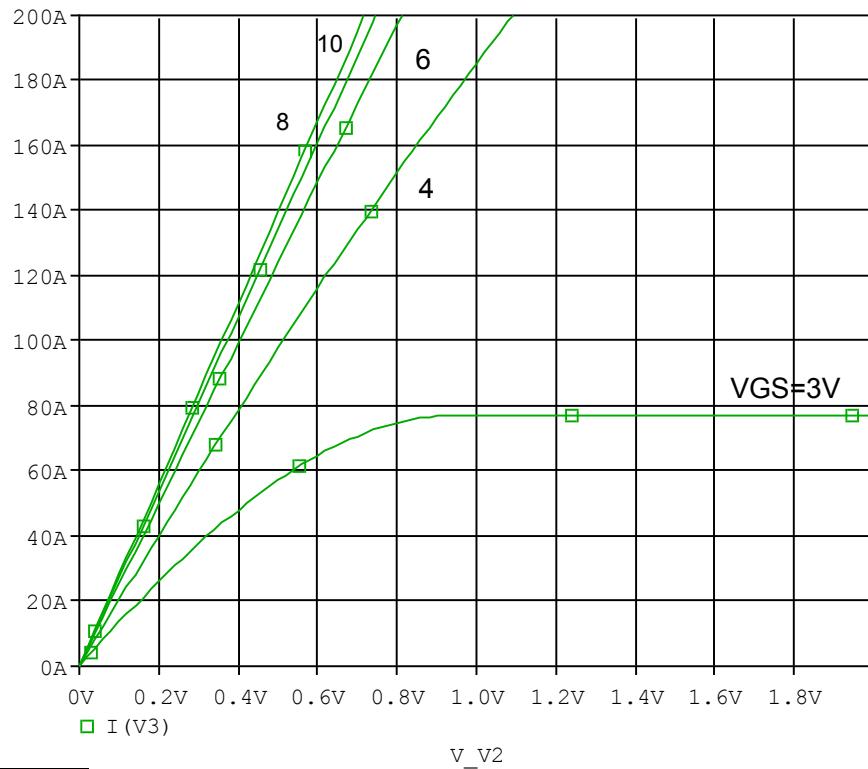


Simulation Result

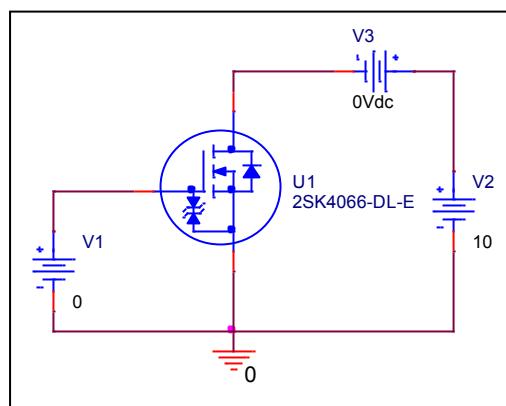
$I_D=50A, V_{DD}=30V$ $V_{GS}=0/10V$		Measurement	Simulation	Error (%)
td(on)	ns	80.000	80.074	0.09

Output Characteristic

Circuit Simulation result

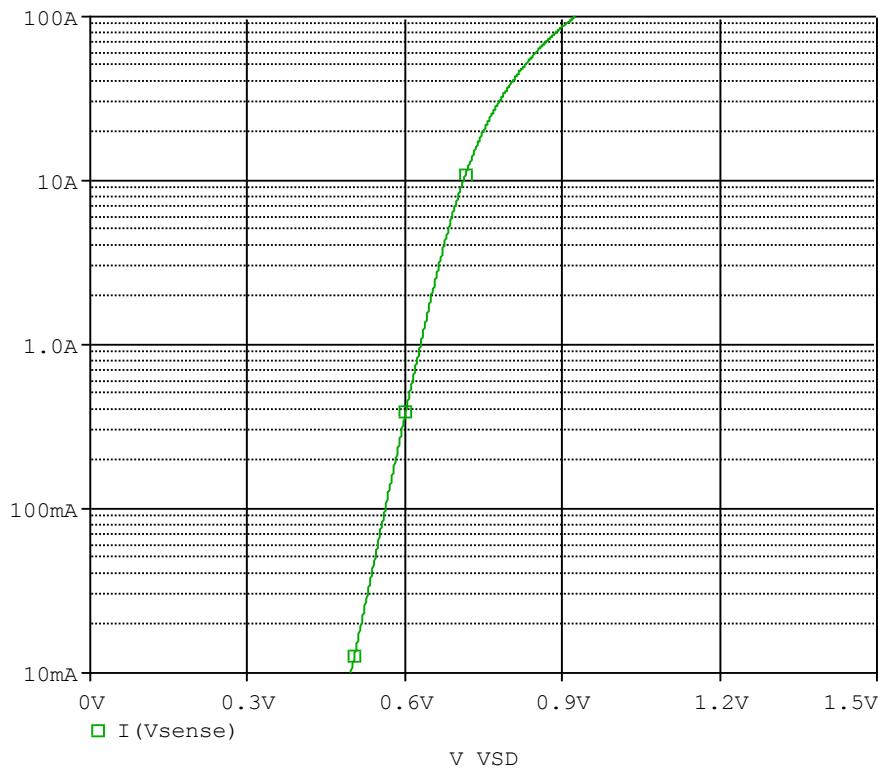


Evaluation circuit

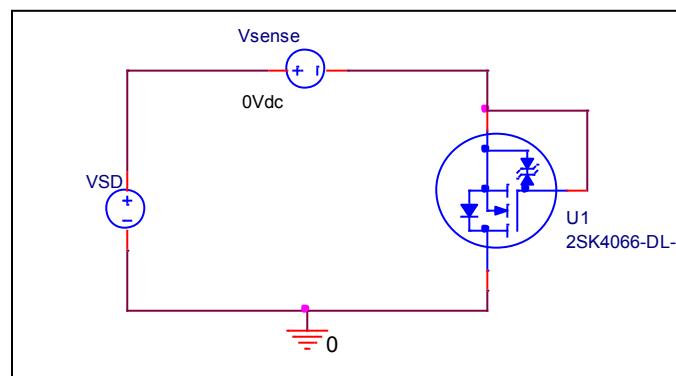


Forward Current Characteristic

Circuit Simulation Result

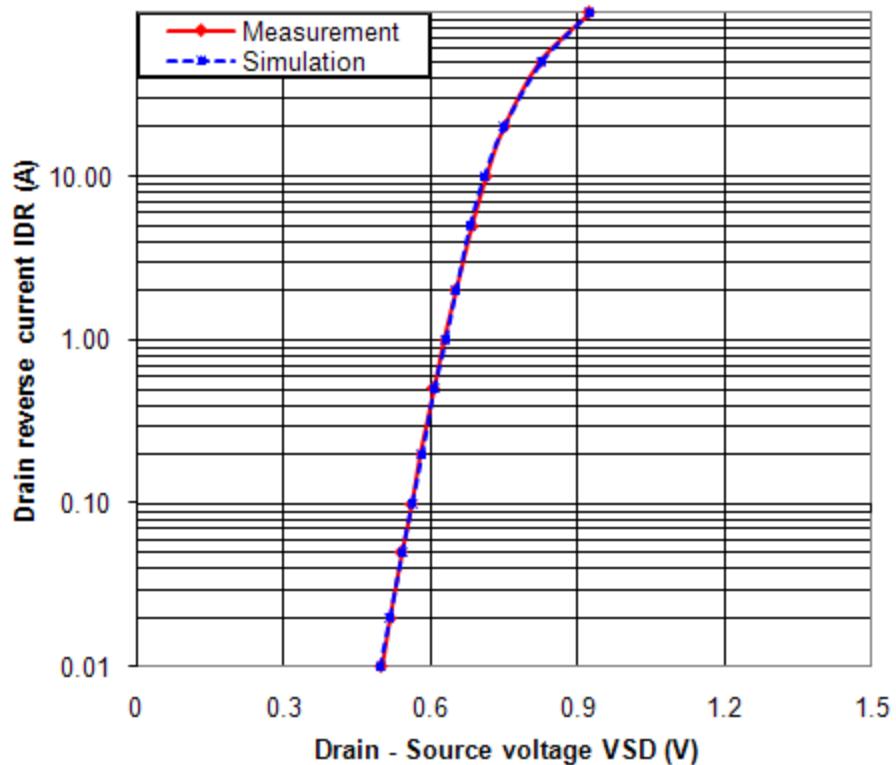


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

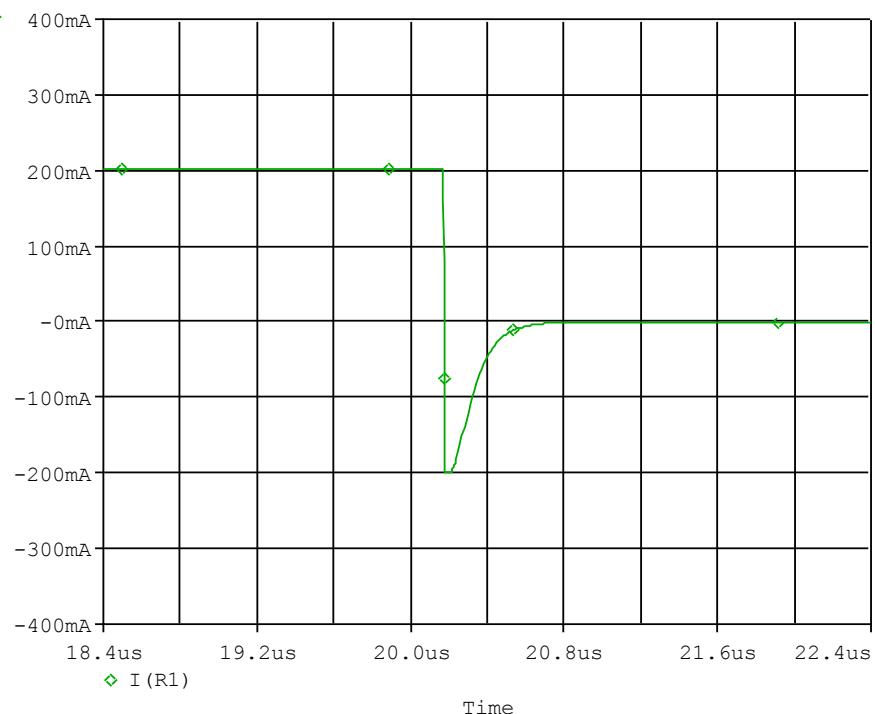


Simulation Result

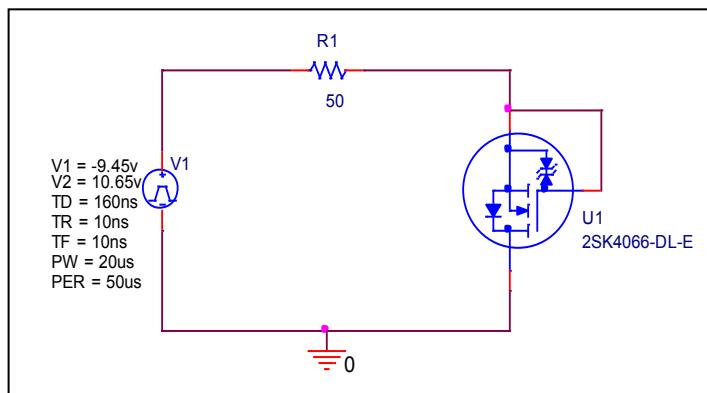
IDR(A)	VSD(V)		%Error
	Measurement	Simulation	
0.01	0.500	0.497	-0.60
0.02	0.518	0.516	-0.39
0.05	0.541	0.543	0.37
0.10	0.562	0.563	0.18
0.20	0.580	0.582	0.34
0.50	0.607	0.609	0.33
1.00	0.628	0.630	0.32
2.00	0.650	0.651	0.15
5.00	0.685	0.682	-0.44
10.00	0.715	0.711	-0.56
20.00	0.750	0.749	-0.13
50.00	0.825	0.827	0.24
100.00	0.925	0.924	-0.11

Reverse Recovery Characteristics

Circuit Simulation Result



Evaluation Circuit

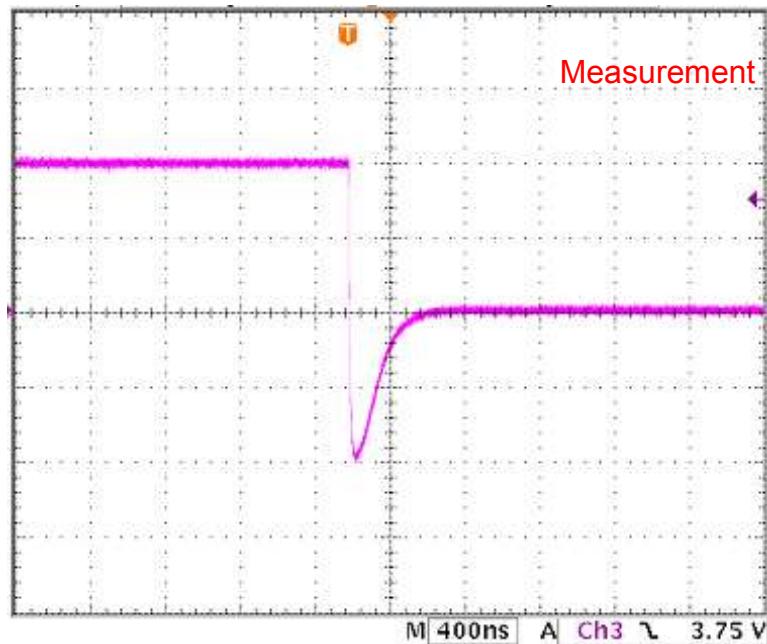


Compare Measurement vs. Simulation

		Measurement	Simulation	Error (%)
trj	ns	32.000	32.700	2.19

Reverse Recovery Characteristic

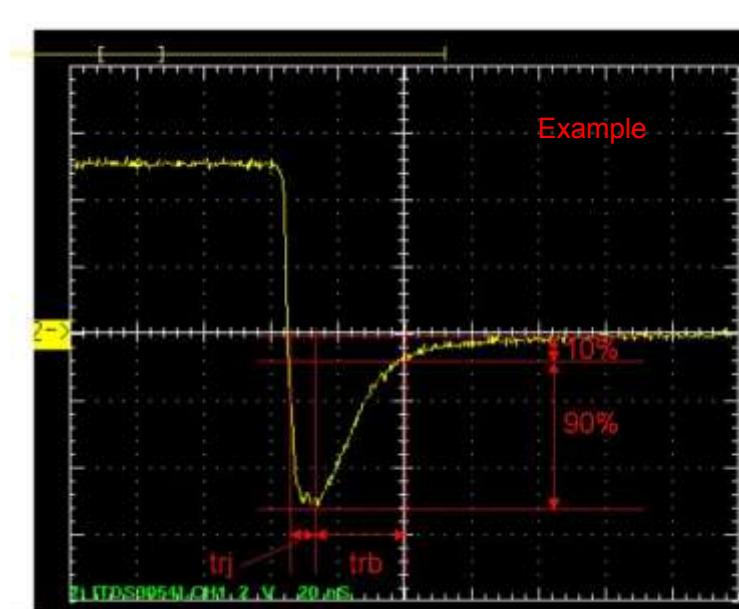
Reference



Trj= 32 (ns)

Trb= 192 (ns)

Conditions: Ifwd=Irev=0.2(A), RI=50

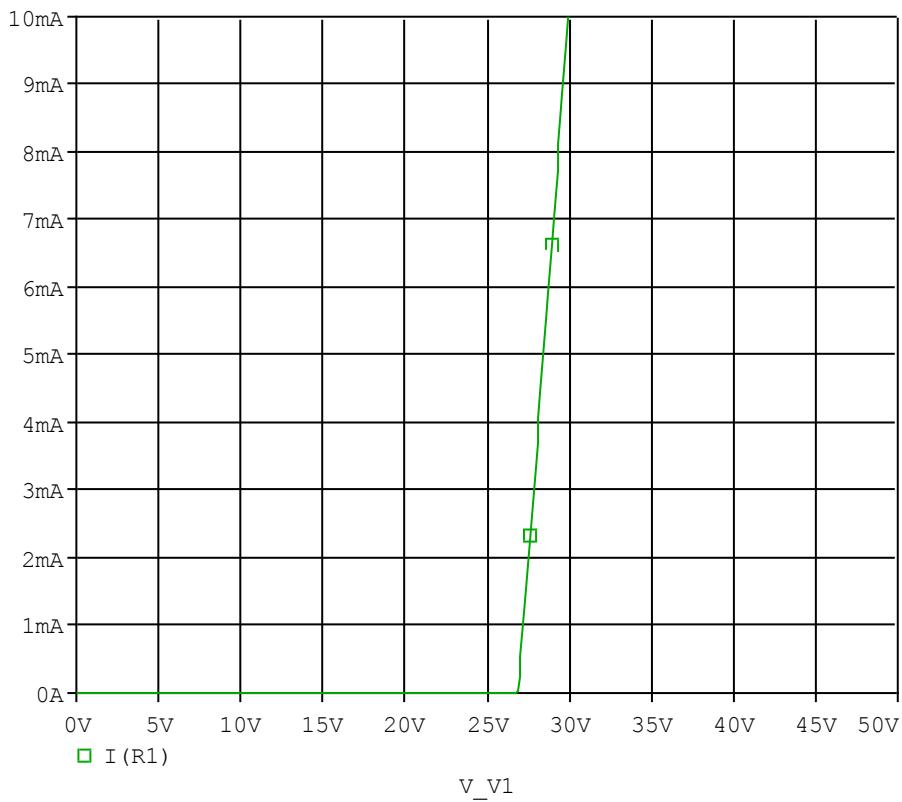


Relation between trj and trb

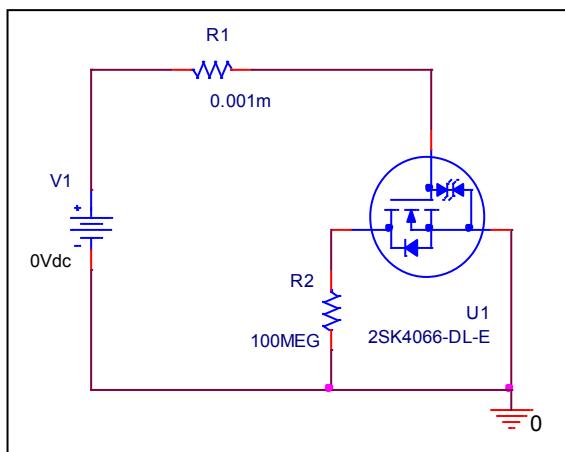
ESD PROTECTION DIODE SPICE MODEL

Zener Voltage Characteristic

Circuit Simulation Result



Evaluation Circuit



Zener Voltage Characteristic

Reference

